RT2C00M

COMPOSITE TRANSISTOR FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

DESCRIPTION

RT2C00M is a composite transistor built with two 2SC3052 chips in SC-88A package.

FEATURE

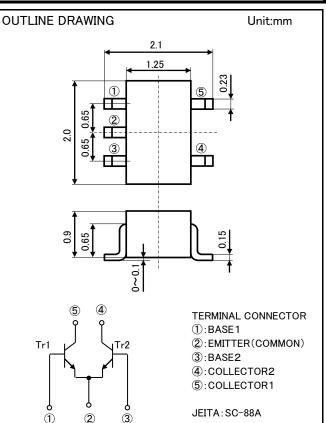
Silicon NPN epitaxial type

Each transistor elements are independent.

Mini package for easy mounting

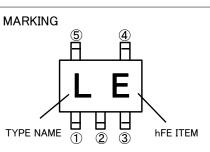
APPLICATION

For low frequency amplify application



MAXIMUM RATINGS (Ta=25°C) (Tr1,Tr2 COMMON)

Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector to Base voltage	50	V
V_{EBO}	Emitter to Base voltage	6	V
V _{CEO}	Collector to Emitter voltage	50	V
Ιc	Collector current	200	mA
PT	Total dissipation	200	mW
Tj	Junction temperature	+150	°C
T_{stg}	Storage temperature	-55~+150	°C



JEDEC: -

ELECTRICAL CHARACTERISTICS (Ta=25°C)(Tr1,Tr2 COMMON)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Тур	Max	Unit
V _{(BR)CEO}	Collector to Emitter breakdown voltage	$I_{c}=100 \mu A, R_{BE}=\infty$	50	_	-	V
I _{CBO}	Collector cut off current	V_{CB} =50V, I _E =0mA	-	-	0.1	μA
\mathbf{I}_{EBO}	Emitter cut off current	V _{EB} =6V, I _c =0mA	-	-	0.1	μA
h _{FE} *	DC forward current gain	V _{CE} =6V, I _C =-1mA	150	_	500	-
h _{FE}	DC forward current gain	V _{CE} =6V, I _C =0.1mA	90	-	-	-
$V_{\text{CE}(\text{sat})}$	Collector to Emitter saturation voltage	I _c =100mA, I _B =10mA	-	-	0.3	V
f_{T}	Gain band width product	V_{ce} =6V, I _e =10mA	-	200	-	MHz
Cob	Collector output capacitance	V_{CB} =6V, I _E =0mA, f=1MHz	-	2.5	_	pF
NF	Noise figure	$V_{\text{CE}}\text{=}6\text{V},~I_{\text{E}}\text{=}\text{-}0.1\text{mA},~\text{f}\text{=}100\text{Hz},~\text{R}_{\text{G}}\text{=}2\text{k}\Omega$	_	-	15	dB

 $\boldsymbol{*}:$ It shows h_{FE} classification in right table.

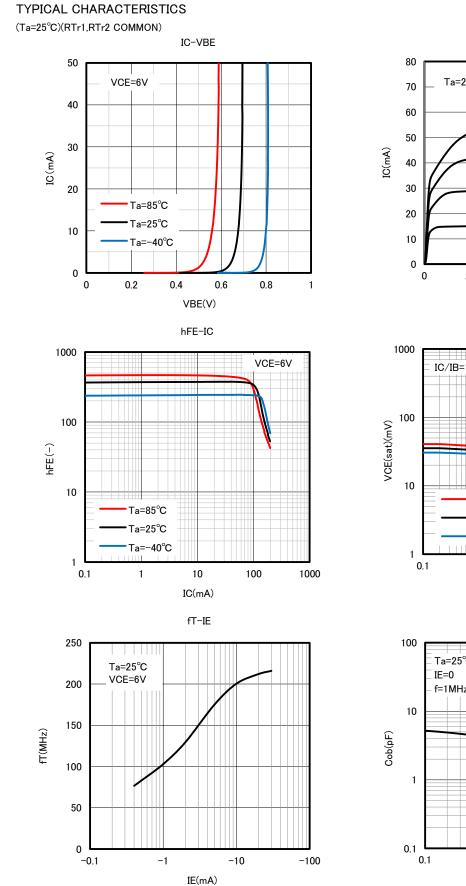
ITEM	E	F
hFE	150~300	250~500

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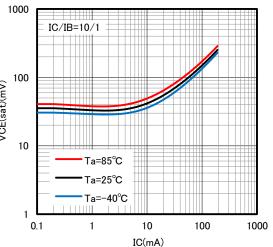
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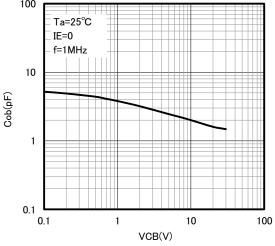
IC-VCE







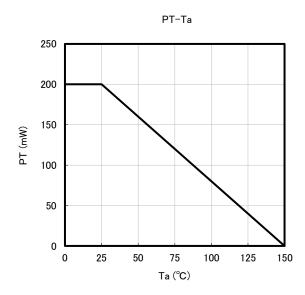




ISAHAYA ELECTRONICS CORPORATION

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